MOC3020X, MOC3021X, MOC3022X, MOC3023X
MOC3020, MOC3021, MOC3022, MOC3023

ISOCOM COMPONENTS

OPTICALLY COUPLED BILATERAL SWITCH NON-ZERO CROSSING TRIAC

ROHS COMPLIANT

APPROVALS

- UL recognised, File No. E91231 under Package System 'KK'

'X' SPECIFICATION APPROVALS

- VDE 0884 in 3 available lead forms : -
  - STD
  - G form
  - SMD approved to CECC 00802

DESCRIPTION

The MOC302_ series are optically coupled isolators consisting of a Gallium Arsenide infrared emitting diode coupled with a light activated silicon bilateral switch performing the functions of a triac mounted in a standard 6 pin dual-in-line package.

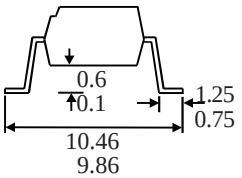
FEATURE

- Options :-
  10mm lead spread - add G after part no.
  Surface mount - add SM after part no.
  Tape&reel - add SMT&R after part no.
- High Isolation Voltage (5.3kV$_{RMS}$,7.5kV$_{PK}$)
- 400V Peak Blocking Voltage
- All electrical parameters 100% tested
- Custom electrical selections available

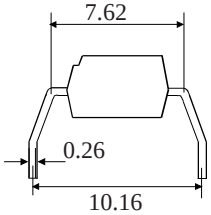
APPLICATIONS

- CRTs
- Power Triac Driver
- Motors
- Consumer appliances
- Printers

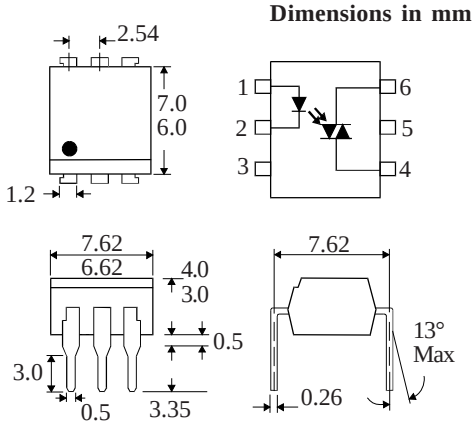
OPTION SM
SURFACE MOUNT



OPTION G



Dimensions in mm



ABSOLUTE MAXIMUM RATINGS
(25 °C unless otherwise noted)

Storage Temperature	-55^{0}C - +150^{0}C
Operating Temperature	-40^{0}C - +100^{0}C
Lead Soldering Temperature (1.6mm from case for 10 seconds)	260^{0}C

INPUT DIODE

Forward Current	50mA
Reverse Voltage	6V
Power Dissipation (derate linearly 0.93mW/^{0}C above 25^{0}C)	70mW

OUTPUT PHOTO TRIAC

Off-State Output Terminal Voltage	400V
Forward Current (Peak)	1A
Power Dissipation (derate linearly 4.0mW/^{0}C above 25^{0}C)	300mW

POWER DISSIPATION

Total Power Dissipation (derate linearly 4.4mW/^{0}C above 25^{0}C)	330mW

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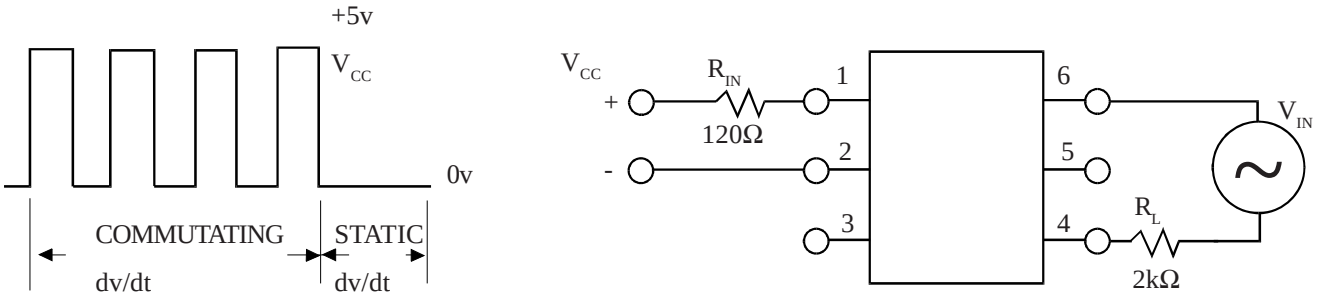
ELECTRICAL CHARACTERISTICS (T_A = 25°C Unless otherwise noted)

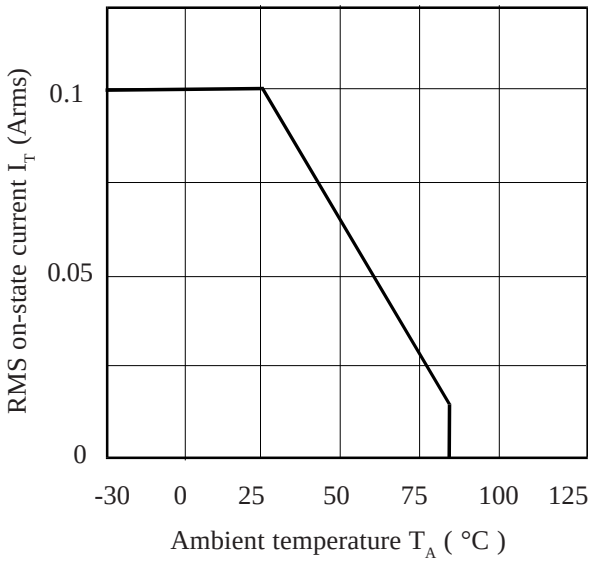
PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F)		1.2	1.5	V	I_F = 10mA
	Reverse Current (I_R)			100	µA	V_R =6V
Output	Peak Off-state Current (I_{DRM})			100	nA	V_{DRM} = 400V (note 1)
	Peak Blocking Voltage (V_{DRM})	400			V	I_{DRM} = 100nA
	On-state Voltage (V_{TM})		1.5	3.0	V	I_{TM} = 100mA (peak)
	Critical rate of rise of off-state Voltage (dv/dt) (note 1)		10		V/µs	
	Critical rate of rise of commutating Voltage (dv/dt) (note 1)	0.1	0.2		V/µs	I load = 15mA, V_{IN} = 30V (fig 1.)
Coupled	Input Current to Trigger (I_{FT})(note 2)					
	MOC3020			30	mA	V_D = 3V (note 2)
	MOC3021			15	mA	
	MOC3022			10	mA	
	MOC3023			5	mA	
	Holding Current , either direction (I_H)	100			µA	
	Input to Output Isolation Voltage V_{ISO}	5300			V_{RMS}	See note 3
		7500			V_{PK}	See note 3

Note 1. Test voltage must be applied within dv/dt rating.
Note 2. Guaranteed to trigger at an I_F value less than or equal to max. I_{FT}, recommended I_F lies between Rated I_{FT} and absolute max. I_{FT}.
Note 3. Measured with input leads shorted together and output leads shorted together.

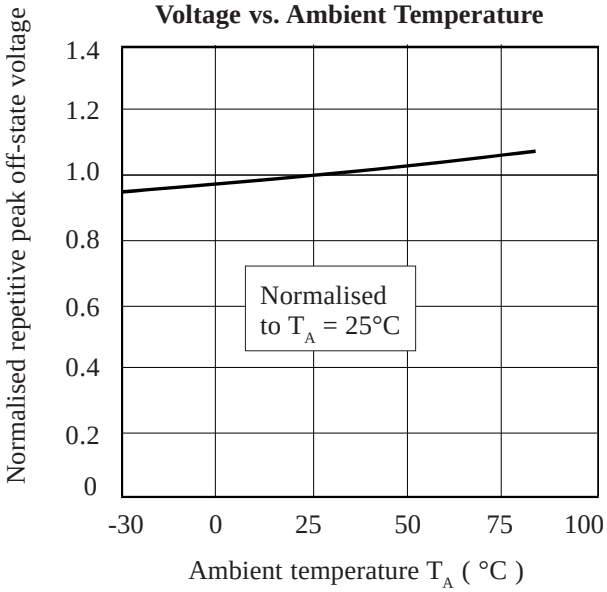
FIGURE 1



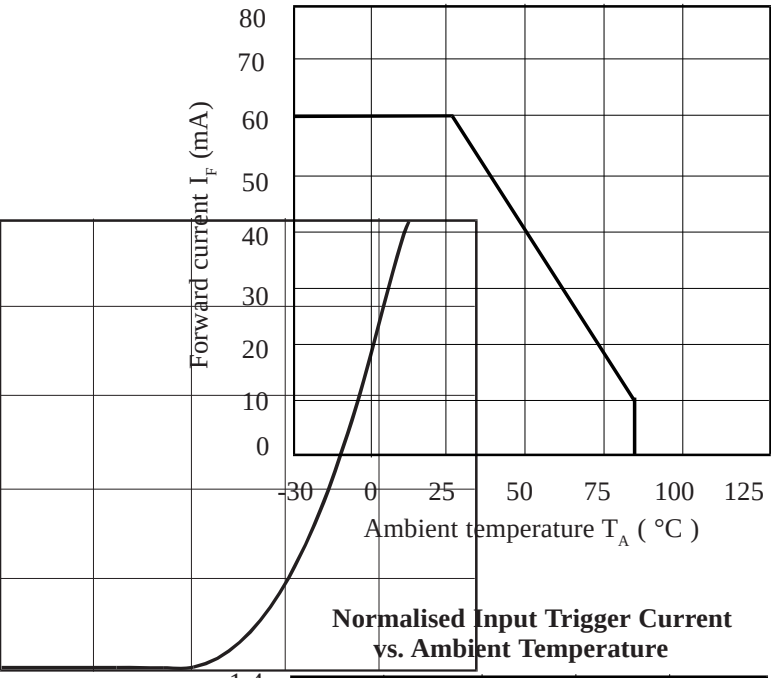
RMS On-state Current vs. Ambient Temperature



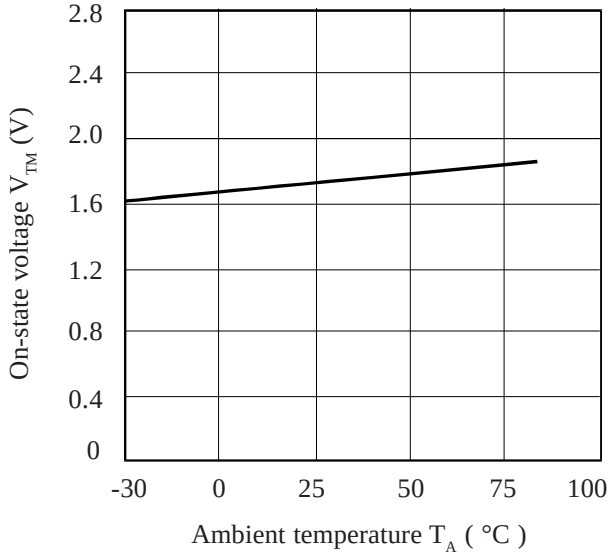
Normalised Repetitive Peak Off-state Voltage vs. Ambient Temperature



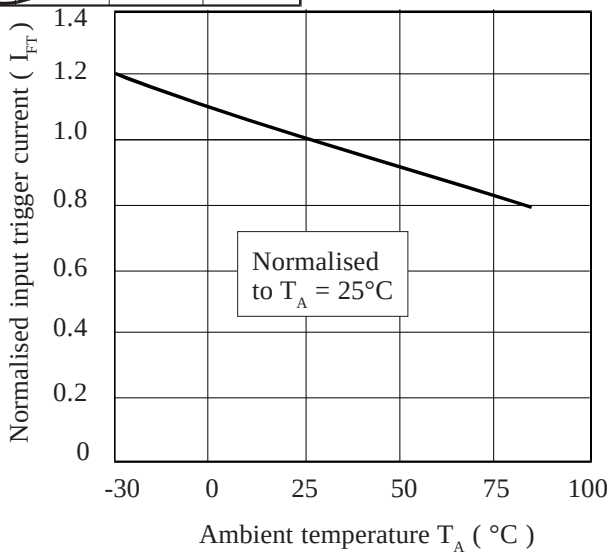
Forward Current vs. Ambient Temperature



On-state Voltage vs. Ambient Temperature



Normalised Input Trigger Current vs. Ambient Temperature



On-state Current vs. On-state Voltage